TOSHIBA CRG01,CRG02

TOSHIBA RECTIFIER SILICON DIFFUSED TYPE

CRG01, CRG02

GENERAL PURPOSE RECTIFIER APPLICATIONS

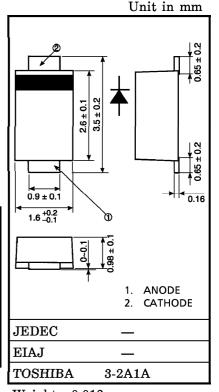
Average Forward Current: IF(AV)=0.7A

Repetitive Peak Reverse Voltage: VRRM=100, 400V

: "S-FLAT" (Toshiba designation) Small Package

MAXIMUM RATINGS

CHARACTERISTI	SYMBOL	RATING	UNIT		
Repetitive Peak Reverse Voltage	V _{RRM}	100 400	V		
Average Forward Current	I _{F (AV)}	0.7	A		
Peak One Cycle Surge For Current (Non-Repetitive)	I_{FSM}	15 (50Hz) 16.5 (60Hz)	A		
Junction Temperature	T_{j}	-40~150	$^{\circ}\mathrm{C}$		
Storage Temperature Rang	$\mathrm{T_{stg}}$	-40~150	°C		



Weight: 0.013g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	TYP.	MAX.	UNIT
	V _{FM (1)} I _{FM} =0.1A V _{FM (2)} I _{FM} =0.7A		0.88	_	
Peak Forward Voltage			-	1.1	V
	V _{FM (3)}	$I_{\text{FM}} = 1.0 \text{A}$		_	
Repetitive Peak Reverse Current	I_{RRM}	V _{RRM} =Rated	ı	10	μ A
Thermal Resistance	rth (j-a)	On ceramic substrate		65	°C/W
Thermal Resistance	(DC)	On glass-epoxy substrate		130	0 / W

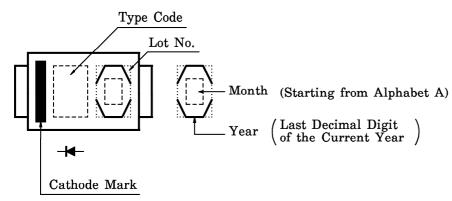
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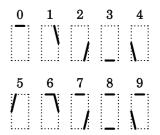
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MARKING



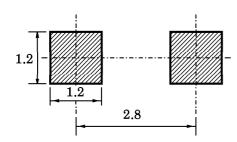
FOLLOWING	i INDICATES
THE DATE (OF MANUFACTURE

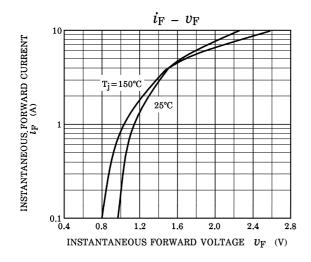


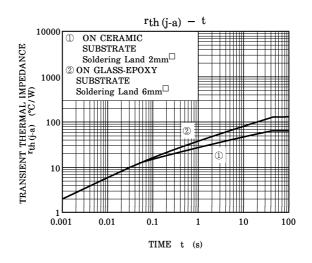
TYPE	CODE
CRG01	G1
CRG02	G2

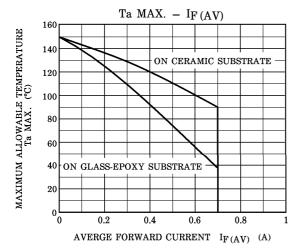
STANDARD SOLDERING PAD

Unit: mm









	ON CERAMIC SUBSTRATE	ON GLASS- EPOXY SUBSTRATE
Soldering Land	2mm [□]	6mm□
Substrate Size	50mm [□]	50mm [□]
Substrate Thickness	0.64t	1.6t

	00	SURGE FORWARD CURRENT (NON – REPETITIVE)															
HE FORWARD CURRENT	30						-				Ta=25°C, f=50Hz Half Sine Waveform						z
	25										Wav	6101			I		1
	20														1		
	15														1		+
	10				/	_	_	_	1	_					7		-
	5								1						1		1
-	0	l							1(0] 100
		NUMBER OF CYCLES															